# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





### **10W AUDIO AMPLIFIER WITH MUTING**

#### DESCRIPTION

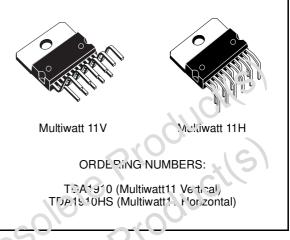
The TDA 1910 is a monolithic integrated circuit in MULTIWATT® package, intended for use in Hi-Fi audio power applications, as high quality TV sets. The TDA 1910 meets the DIN 45500 (d = 0.5%) guaranteed output power of 10W when used at 24V/4W. At 24V/8W the output power is 7W min. Features:

- muting facility
- protection against chip over temperature
- very low noise
- high supply voltage rejection
- low "switch-on" noise.

The TDA 1910 is assembled in MULTIWATT® package that offers:

- easy assembly
- simple heatsink

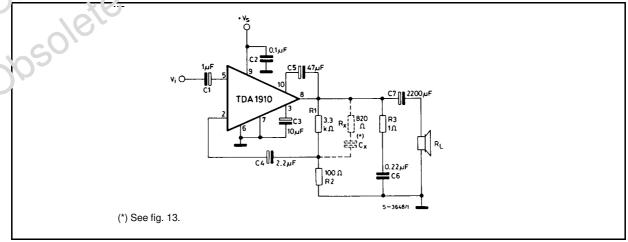
#### ABSOLUTE MAXIMUM RATINGS



- space and cost saving - high reliab;"ty

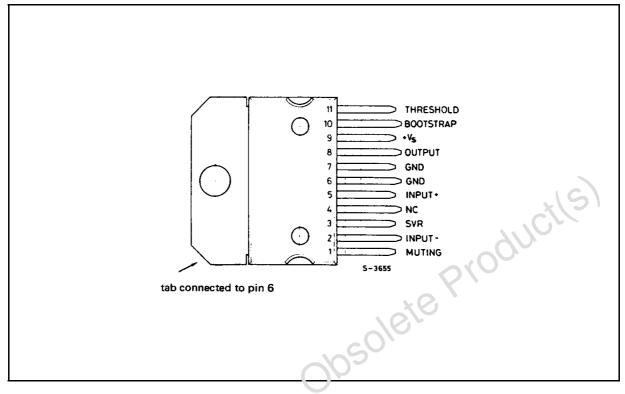
Symbol	o <sub>&amp;</sub> rameter	Value	Unit
Vs	Supply voltage	30	V
lo	Output peak current (non repetitive)	3.5	А
lo	Output peak current (repetitive)	3.0	А
Vi	Input voira je	$0 \text{ to } + \text{V}_{\text{s}}$	V
Vi	Different al input voltage	± 7	V
V <sub>11</sub>	Muting thresold voltage	Vs	V
Ptot	Puver dissipation $P_{t}T_{CRF} = 90^{\circ}C$	20	W
T <sub>stç</sub> , T	Storage and juration temperature	-40 to 150	°C

#### **TEST CIRCUIT**

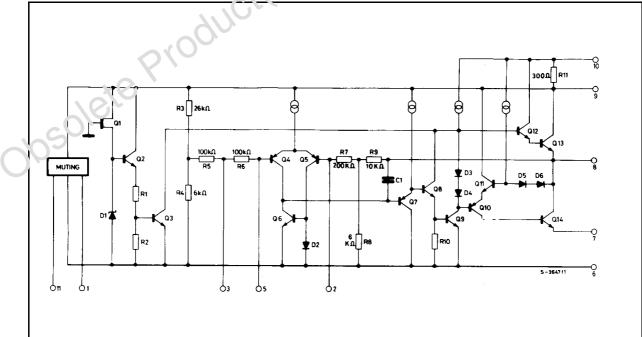


September 2003

#### **PIN CONNECTION** (Top view)



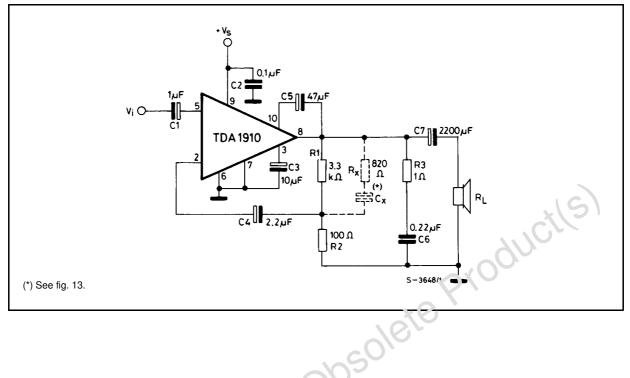




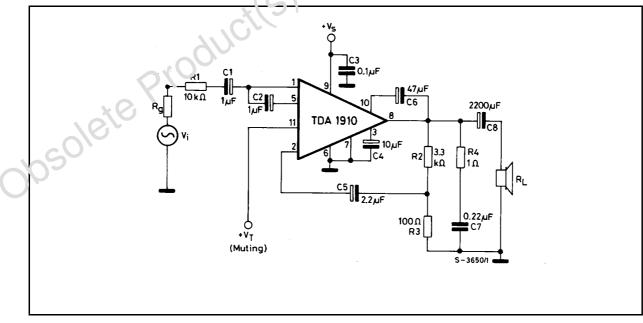
57

2/15

#### **TEST CIRCUIT**



**MUTING CIRCUIT** 



#### THERMAL DATA

Symbol	Parameter	Value	Unit
R <sub>th j-case</sub>	Thermal resistance junction-case max	3	°C/W

# **ELECTRICAL CHARACTERISTICS** (Refer to the test circuit, $T_{amb} = 25 \text{ °C}$ , $R_{th}$ (heatsink) = 4°C/W, unless otherwise specified)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vs	Supply voltage		8		30	v
Vo	Quiescent output voltage	V <sub>s</sub> = 18V V <sub>s</sub> = 24V	8.3 11.5	9.2 12.4	10 13.4	6
I <sub>d</sub>	Quiescent drain current	V <sub>s</sub> = 18V V <sub>s</sub> = 24V		<u>'9</u> 2	32 35	mA
V <sub>CE sat</sub>	Output stage saturation voltage	I <sub>C</sub> = 2A	21	1		v
		I <sub>C</sub> = 3A		1.6		•
Po	Output power	$ \begin{array}{ll} d = 0.5\% & f = 40 \text{ to } 15,000\text{Hz} \\ V_s = 18V & P_{1-}^{*} + 4\Omega \\ V_s = 24V & A_L = 4\Omega \\ V_s = 24V & R_L = 8\Omega \end{array} $	6.5 10 7	7 12 7.5		W
	ctl		8.5 15 9	9.5 17 10		
d	Harmonic distortion			0.2 0.2 0.2	0.5 0.5 0.5	%
020	Intermodulation distortion	$V_{s} = 24V \qquad R_{L} = 4\Omega \qquad P_{o} = 10W \\ f_{1} = 250 \text{ Hz} \qquad f_{2} = 8 \text{ KHz} \\ (\text{DIN 45500})$		0.2		%
Vi	Input sensitivity	$\begin{array}{lll} F = 1 \ KHz, \\ V_{s} = 18V \\ v_{s} = 24V \\ V_{s} = 24V \\ \end{array} \begin{array}{lll} R_{L} = 4\Omega \\ R_{L} = 4\Omega \\ R_{L} = 4\Omega \\ P_{o} = 12 \\ P_{o} = 7.5W \end{array}$		170 220 245		mV
Vi	Input saturation voltage (rms)	V <sub>s</sub> = 18V V <sub>s</sub> = 24V	1.8 2.4			V
Ri	Input resistance (pin 5)	f = 1 KHz	60	100		KΩ
l <sub>d</sub>	Drain current	$ \begin{array}{ll} V_{s}=24V & f=1 \ KHz \\ R_{L}=4\Omega & P_{o}=12W \\ RL=8\Omega & P_{o}=7.5W \end{array} $		820 475		mA

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
h	Efficiency	$ \begin{array}{ll} V_{s}=24V & f=1\ KHz \\ R_{L}=4\Omega & P_{o}=12W \\ R_{L}=8\Omega & P_{o}=7.5W \end{array} $		62 65		%
BW	Small signal bandwidth	$V_{s} = 24V \qquad R_{L} = 4\Omega \qquad P_{o} = 1W$	10	) to 120,0	00	Hz
BW	Power bandwidth	$ \begin{array}{ll} V_s = 24V & R_L = 4\Omega \\ P_o = 12W & d \leq 5\% \end{array} $	4	0 to 15,0	00	Hz
Gv	Voltage gain (open loop)	f = 1 KHz		75		dB
Gv	Voltage gain (closed loop)		29.5	30	30.5	αB
e <sub>N</sub>	Total input noise	$\begin{array}{l} R_g = 50\Omega \\ R_g = 1K\Omega \\ R_g = 10K\Omega \end{array} (^{\circ})$		1.2 1.3 1.5	3.0 3.2 4.0	μV
		$\begin{array}{l} R_g = 50\Omega \\ R_g = 1K\Omega \\ R_g = 10K\Omega \end{array} (^{\circ\circ})$		2.0 2.0 2.2	5.0 5.2 6.0	μV
S/N	Signal to noise ratio		97	103 105		dB
		$ \begin{array}{c} R_{L} = 4\Omega \\ R_{g} = 10K\Omega \\ R_{g} = 0 \end{array} \left( \begin{array}{c} \circ \circ \end{array} \right)                               $	93	100 100		dB
SVR	Supply voltage rejection	$v_s = 24V$ RL = 4 $\Omega$ f <sub>pple</sub> = 100 Hz Rg = 10 K $\Omega$	50	60		dB
$T_{sd}$	Thermal sjut-down case (*) temperature	P <sub>tot</sub> = 8W	110	125		°C

#### ELECTRICAL CHARACTERISTICS (continued)

### MUTING FUNCTION (Refer to Muting circuit)

VT	Metting-off threshold voltage (pin 11)		1.9		4.7	V
Y <sub>1</sub>	Muting-on threshold voltage		0		1.3	v
03	(pin 11)		6		Vs	-
R <sub>1</sub>	Input resistance (pin 1)	Muting off	80	200		KΩ
		Muting on		10	30	Ω
R <sub>11</sub>	Input resistance (pin 11)		150			KΩ
A <sub>T</sub>	Muting attenuation	$R_g + R_1 = 10 \text{ K}\Omega$	50	60		dB

Note : (°) Weighting filter = curve A. (°°) Filter with noise bandwidth: 22 Hz to 22 KHz. (\*) See fig. 29 and fig. 30.

Figure 1. Quiescent output voltage vs. supply voltage

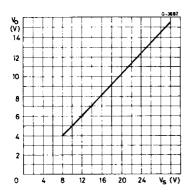


Figure 2. Quiescent drain current vs. supply voltage

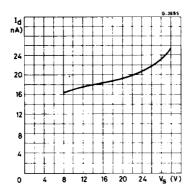


Figure 3. Open loop frequency response

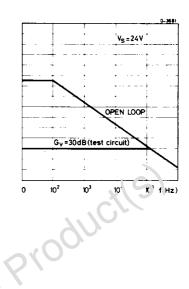


Figure 4. Output power vs. supply voltage

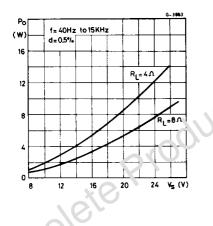


Figure 5. Output power vs. supply voltage

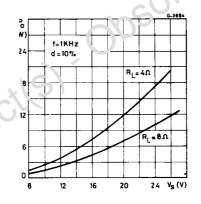


Figure 6. Distortion vs. output power

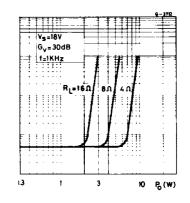


Figure 7. Distortion vs. output power

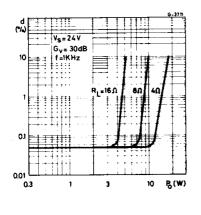


Figure 8. Output power vs. frequency

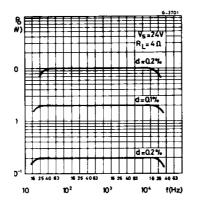
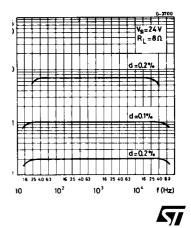


Figure 9. Output power vs. frequency



6/15

Figure 10. Output power vs. input voltage

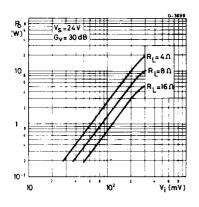
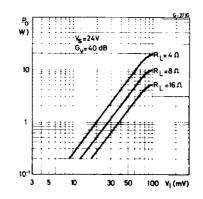


Figure 11. Output power vs. input voltage



### Figure 12. Total input noise vs. source resistance

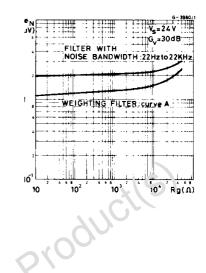


Figure 13. Values of capacitor Cx vs. bandwidth (BW) and gain (G $_V$ )

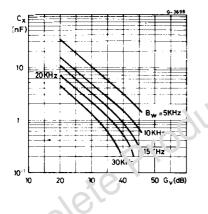


Figure 14. Supply voltage rejection vs. voltage gain

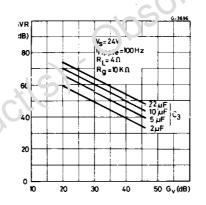


Figure 15. Supply voltage rejection vs. source resistance

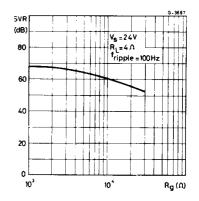


Figure 16. Power dissipation and efficiency vs. output power

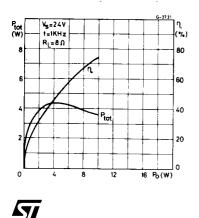


Figure 17. Power dissipation and efficiency vs. output power

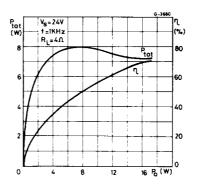
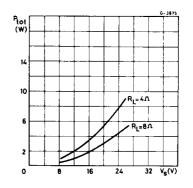
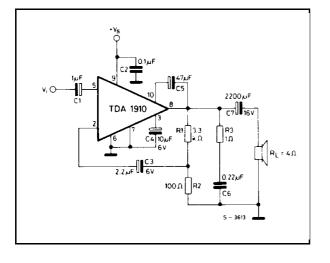


Figure 18. Max power dissipation vs. supply voltage



#### **APPLICATION INFORMATION**



#### Figure 19. Application circuit without muting

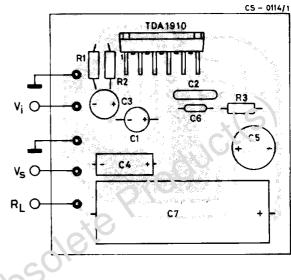
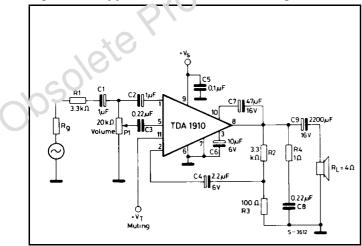


Figure 20. PC board and component lay-out of the circuit of fig. 19 (1:1 scale)

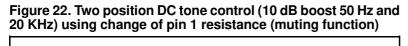
#### Figure 21. Application circuit with muting

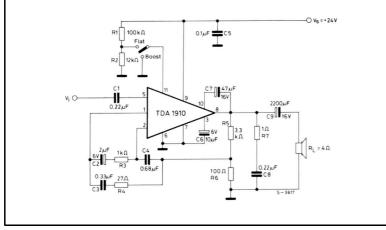


Performance (circuits of fig. 19 and 21)  $P_o$  = 12W (40 to 15000 Hz, d  $\leq$  0.5%)  $V_s$  = 24V  $I_d$  = 0.82A  $G_v$  = 30 dB



#### **APPLICATION INFORMATION (continued)**





## Figure 23. Frequency response of the circuit of fig. 22

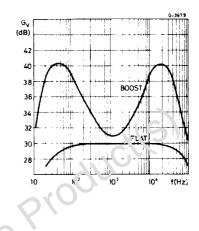


Figure 24. 10 dB 50 Hz boos tone control using change of pin 1 resistance (muting function)

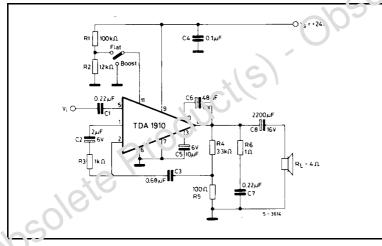
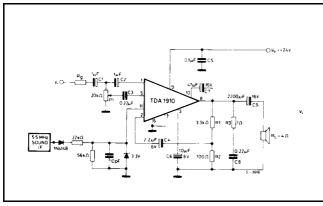
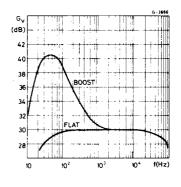


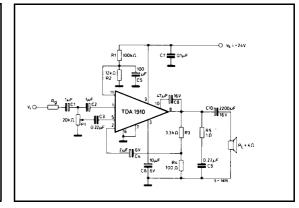
Figure 26. Squelch function in TV applications



#### Figure 25. Frequency response of the circuit of fig. 24



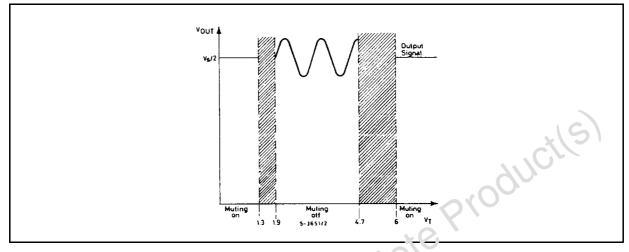




#### **MUTING FUNCTION**

The output signal can be inhibited applying a DC voltage  $V_T$  to pin 11, as shown in fig. 28

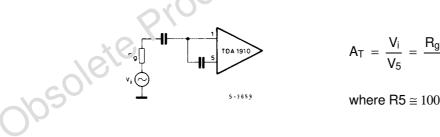
#### Figure 28



The input resistance at pin 1 depends on the threshold voltage Vr at pin 11 and is typically.

$R_1 = 200 \text{ K}\Omega$	@	$1.9V \leq V_T \leq 4.7V$	งาบ ting-off	ff
$R1 = 10 \Omega$	@	$\begin{array}{l} 0V \leq V_T \leq 1.3V \\ 6V \leq V_T \leq V_s \end{array}$	muting-on	

Referring to the following input stage the obssible attenuation of the input signal and therefore of the output signal can be found using the following expression.



Considering Rg = 10 K $\Omega$  the attenuation in the muting-on condition is typically  $A_T = 60$  dB. In the muting-off condition, the attenuation is very low, typically 1.2 dB.

A very low current is necessary to drive the threshold voltage V<sub>T</sub> because the input resistance at pin 11 is greater than 150 K $\Omega$ . The muting function can be used in many cases, when a temporary inhibition of the output signal is requested, for example:

- in switch-on condition, to avoid preamplifier power-on transients (see fig. 27)

 $A_T = \frac{V_i}{V_5} = \frac{R_g + R_5 //R_1}{R_5 //R_1}$ 

where  $R5 \cong 100 \text{ K}\Omega$ 

- during commutations at the input stages.

- during the receiver tuning.

The variable impedance capability at pin 1 can be useful in many applications and we have shown 2 examples in fig. 22 and 24, where it has been used to change the feedback network, obtaining 2 different frequency responses.

۲Z

#### APPLICATION SUGGESTION

The recommended values of the components are those shown on application circuit of fig. 21. Different values can be used. The following table can help the designer.

Î	Component	Raccom.	Purpose	Larger than	Smaller than	Allowed range	
	component	value	i dipose	recommended value	recommended value	Min.	N'ax.
	R <sub>g</sub> + R <sub>1</sub>	10ΚΩ	Input signal imped. for muting operation	Increase of the atte- nuation in muting-on condition. Decrease of the input sensitivity.	Decrease of the attenuation in muting on condition.	uct	5
	R <sub>2</sub>	3.3KΩ	Close loop gain setting.	Increase of gain.	Decrease of gain. Increase culescent current	9 R <sub>3</sub>	
	$R_3$	100Ω	Close loop gain setting.	Decrease of gain.	Increase of gain.		R <sub>2</sub> /9
	R <sub>4</sub>	1Ω	Frequency stability	Danger of ככליוומליסח at hig'ו לרבק יפי icies with ii duc ive loads.			
	P <sub>1</sub>	20ΚΩ	Volume potentiometer.	Increase of the switch-on noise.	Decrease of the input impedance and of the input level.	10KΩ	100ΚΩ
	C1 C2 C3	1 μF 1 μF 0.22μF	Input DC ດາປວupling.		Higher low frequency cutoff.		
	C <sub>4</sub>	2.2µ. <del>-</del>	nverting input DC decoupling.	Increase of the switch-on noise.	Higher low frequency cutoff.	0.1µF	
	C <sub>5</sub>	0.1μF	Supply voltage bypass.		Danger of oscillations.		
	C <sub>6</sub>	10μF	Ripple rejection.	Increase of SVR. Increase of the switch-on time	Degradation of SVR	2.2µF	100µF
	C <sub>7</sub>	47μF	Bootstrap.		Increase of the distor- tion at low frequency.	10µF	100µF
ľ	C <sub>8</sub>	0.22μF	Frequency stability.		Danger of oscillation.		
	C <sub>9</sub>	$\begin{array}{c} 2200 \mu F \\ (R_L = 4 \Omega) \\ 1000 \ \mu F \\ (R_L = 8 \Omega) \end{array}$	Output DC decoupling.		Higher low frequency cutoff.		

Po

(₩

12

10

8

0

#### THERMAL SHUT-DOWN

The presence of a thermal limiting circuit offers the following advantages:

- An overload on the output (even if it is permanent), or an above limit ambient temperature can be easily supported since the T<sub>j</sub> cannot be higher than 150°C.
- 2) The heatskink can have a smaller factor of safety compared with that of a conventional

L

A)

08

06

0.4

02

Tcase(\*C)

Ρ,

w

12 10

8

6

2

0

circuit. There is no possibility of device damage due to high junction temperature.

If for any reason, the junction temperature increases up to 150°C, the thermal shut-down simply reduces the power dissipation and the current consumption.

The maximum allowable power dissipation depends upon the size of the external heatsink (i.e. its thermal resistance); fig. 31 shows this dissipable power as a function of ambient temperature for different thermal resistance.

Figure 31. Maximum allow able

power dissignation vs. ambient



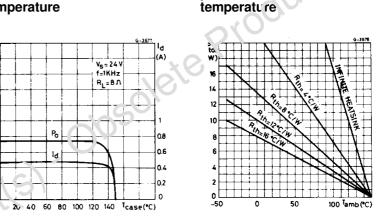
Ð

id

V<sub>5</sub>=24V f =1KHz

RL=4A

Figure 30. Output power and drain current vs. case temperature



#### MOUNTING INSTRUCTIONS

20 40 60 80 100 120 140

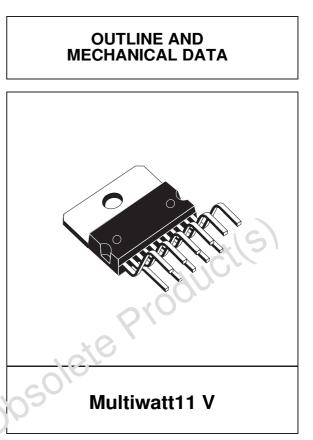
The power dissipated in the circuit must be removed by adding an external heatsink.

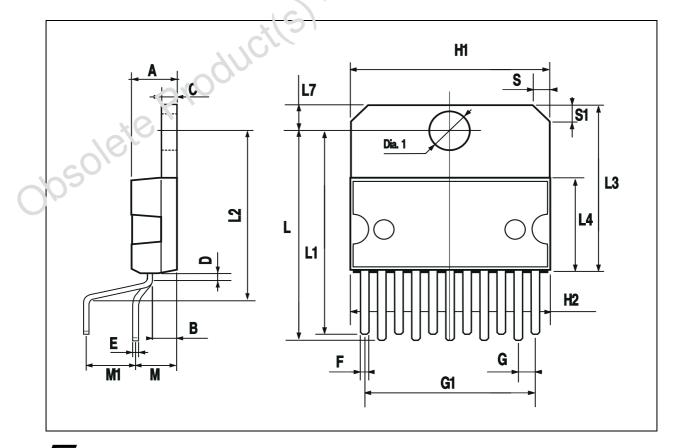
Thanks to the Multiwatt® package attaching the heatsink is very simple, a screw or a compression

spring (clip) being sufficient. Between the heatsink and the package it is better to insert a layer of silicon grease, to optimize the thermal contact; no electrical isolation is needed between the two surfaces.

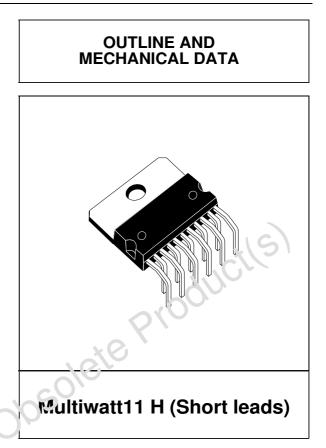


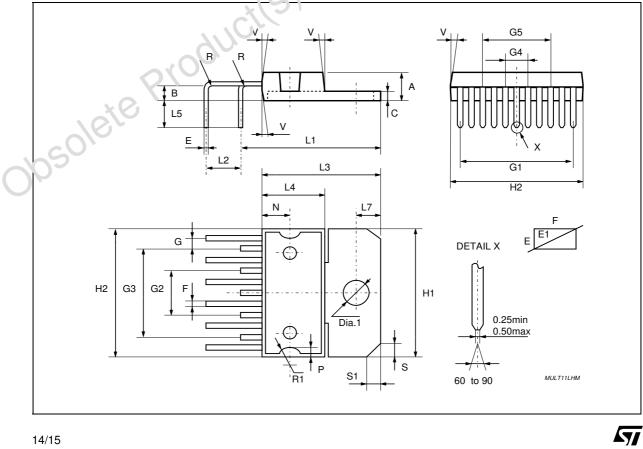
DIM.		mm			inch	
DIN.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			5			0.197
В			2.65			0.104
С			1.6			0.063
D		1			0.039	
Е	0.49		0.55	0.019		0.022
F	0.88		0.95	0.035		0.037
G	1.45	1.7	1.95	0.057	0.067	0.077
G1	16.75	17	17.25	0.659	0.669	0.679
H1	19.6			0.772		
H2			20.2			0.795
L	21.9	22.2	22.5	0.862	0.874	0.886
L1	21.7	22.1	22.5	0.854	0.87	0.886
L2	17.4		18.1	0.685		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
М	4.25	4.55	4.85	0.167	0.179	0.191
M1	4.73	5.08	5.43	0.186	0.200	0.214
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152





DIM.		mm		inch			
DIM.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	4.373	4.5	4.627	0.172	0.177	0.182	
В			2.65			0.104	
С			1.6			0.063	
E	0.49	0.515	0.55	0.019	0.020	0.022	
E1	1.007	1.037	1.07	0.040	0.041	0.042	
F	0.88	0.9	0.95	0.035	0.035	0.037	
G	1.5	1.7	1.9	0.059	0.067	0.075	
G.1	16.82	17.02	17.22	0.662	0.670	0.678	
G2	6.61	6.807	7.01	0.260	0.268	0.276	
G3	13.41	13.61	13.81	0.528	0.536	13.810	
G4	3.2	3.4	3.6	0.126	0.134	0.142	
G5	10.01	10.21	10.41	0.394	0.402	0.410	
H1	19.6			0.772			
H2			20.2			0.795	
L1	19.28	19.58	19.88	0.759	0.771	0.783	
L2	3.61	3.81	4.01	0.142	0.150	0.158	
L3	17.25	17.5	17.75	0.679	0.689	0.699	
L4	10.3	10.6	10.9	0.406	0.417	0.429	
L5 (Inner)	3.4	3.75	4	0.134	0.148	0.157	
L5 (Outer)	3.6	3.9	4.2	0.142	0.154	4.200	
L7	2.65		2.9	0.104		0.114	
R	0.75	1	1.25	0.030	0.039	0.049	
S	1.9		2.6	0.075		0.102	
S1	1.9		2.6	0.075		0.102	
Dia1	3.65		3.85	0.144		0.152	





14/15

Josolete Product(S)-Obsolete Product(S) Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

> The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners

> > © 2003 STMicroelectronics - All rights reserved

STMicroelectronics GROUP OF COMPANIES Australia – Belgium - Brazil - Canada - China – Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States www.st.com

